

# Thyristors sensitive gate

## BTA151 series

### GENERAL DESCRIPTION

Glass passivated, sensitive gate thyristors in a plastic envelope, intended for use in general purpose switching and phase control applications.

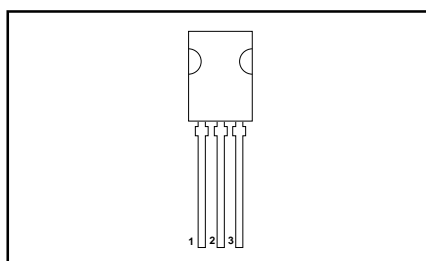
### QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
$V_{DRM}$ , $V_{RRM}$	<b>BTA151-</b> Repetitive peak off-state voltages	<b>500R</b> 500	<b>650R</b> 650	<b>800R</b> 800	V
$I_{T(AV)}$	Average on-state current	7.5	7.5	7.5	A
$I_{T(RMS)}$	RMS on-state current	12	12	12	A
$I_{TSM}$	Non-repetitive peak on-state current	100	100	100	A

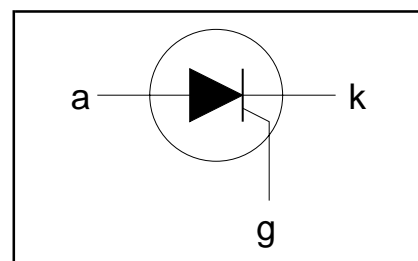
### PINNING - SOT82

PIN	DESCRIPTION
1	cathode
2	anode
3	gate
tab	anode

### PIN CONFIGURATION



### SYMBOL



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
$V_{DRM}$ , $V_{RRM}$	Repetitive peak off-state voltages		-	<b>-500R</b> 500 <sup>1</sup>	<b>-650R</b> 650 <sup>1</sup>	<b>-800R</b> 800	V
$I_{T(AV)}$	Average on-state current	half sine wave; $T_{mb} \leq 109\text{ }^{\circ}\text{C}$	-	7.5			A
$I_{T(RMS)}$	RMS on-state current	all conduction angles	-	12			A
$I_{TSM}$	Non-repetitive peak on-state current	half sine wave; $T_j = 25\text{ }^{\circ}\text{C}$ prior to surge $t = 10\text{ ms}$	-	100			A
$I^2t$	$I^2t$ for fusing	$t = 8.3\text{ ms}$	-	110			A
$di_T/dt$	Repetitive rate of rise of on-state current after triggering	$t = 10\text{ ms}$	-	50			A <sup>2</sup> s
$I_{GM}$	Peak gate current	$I_{TM} = 20\text{ A}$ ; $I_G = 50\text{ mA}$ ; $di_G/dt = 50\text{ mA}/\mu\text{s}$	-	50			A/ $\mu\text{s}$
$V_{GM}$	Peak gate voltage		-	2			A
$V_{RGM}$	Peak reverse gate voltage		-	5			V
$P_{GM}$	Peak gate power		-	12			V
$P_{G(AV)}$	Average gate power		-	5			W
$T_{stg}$	Storage temperature	over any 20 ms period	-	0.5			W
$T_j$	Operating junction temperature		-40	150			$^{\circ}\text{C}$
			-	125			$^{\circ}\text{C}$

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/ $\mu\text{s}$ .

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### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base	in free air	-	-	1.3	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient		-	60	-	K/W

### STATIC CHARACTERISTICS

$T_j = 25\text{ °C}$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_{GT}$	Gate trigger current	$V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$	-	2	4	mA
$I_L$	Latching current	$V_D = 12\text{ V}$ ; $I_{GT} = 0.1\text{ A}$	-	10	40	mA
$I_H$	Holding current	$V_D = 12\text{ V}$ ; $I_{GT} = 0.1\text{ A}$	-	7	16	mA
$V_T$	On-state voltage	$I_T = 23\text{ A}$	-	1.4	1.75	V
$V_{GT}$	Gate trigger voltage	$V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$	-	0.6	1.5	V
$I_D, I_R$	Off-state leakage current	$V_D = V_{DRM(max)}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 125\text{ °C}$	0.25	0.4	-	V
		$V_D = V_{DRM(max)}$ ; $V_R = V_{RRM(max)}$ ; $T_j = 125\text{ °C}$	-	0.1	0.5	mA

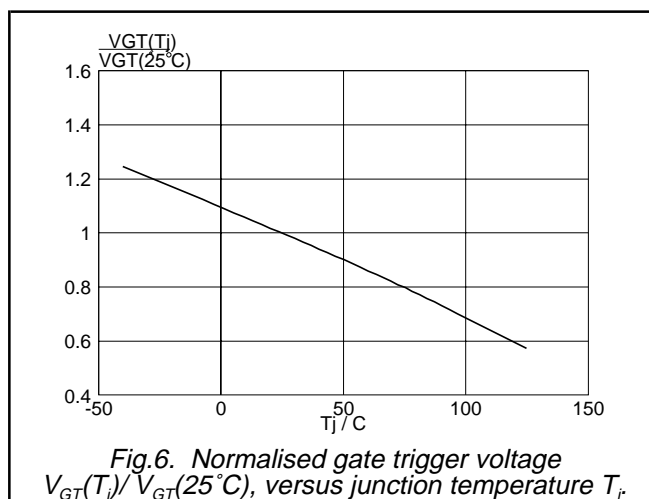
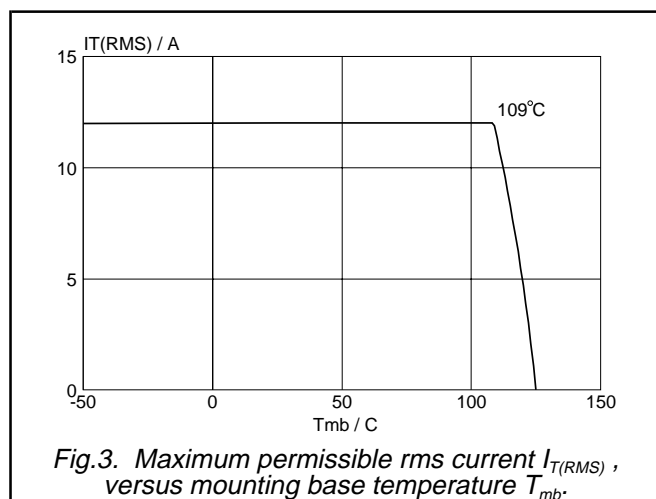
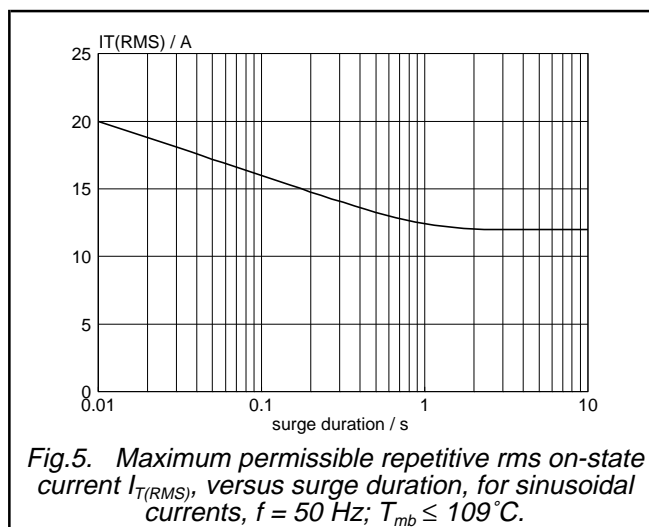
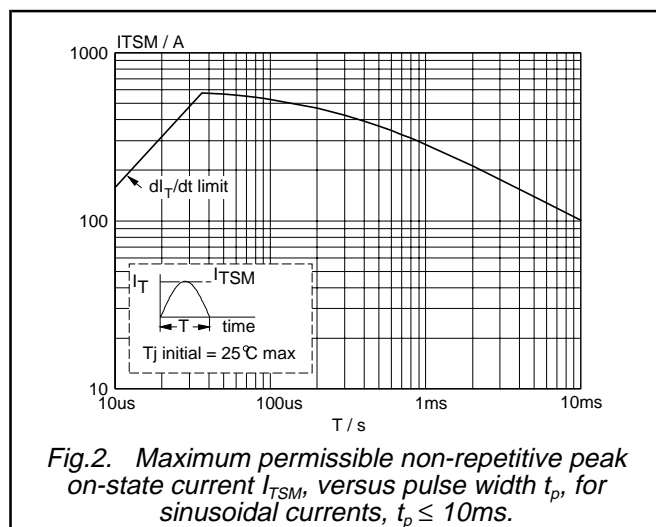
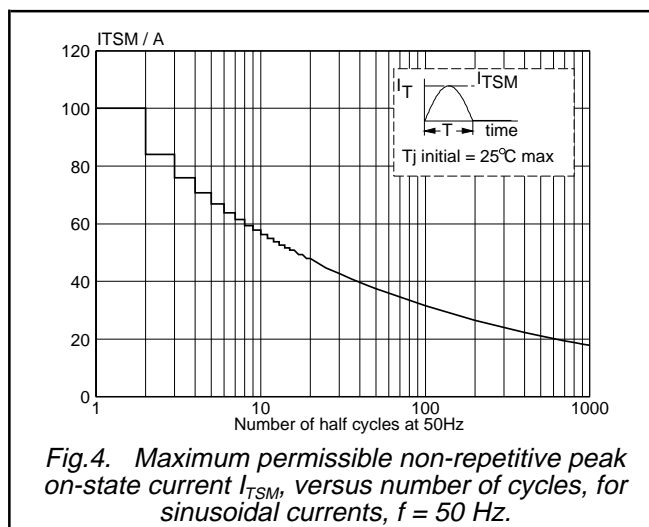
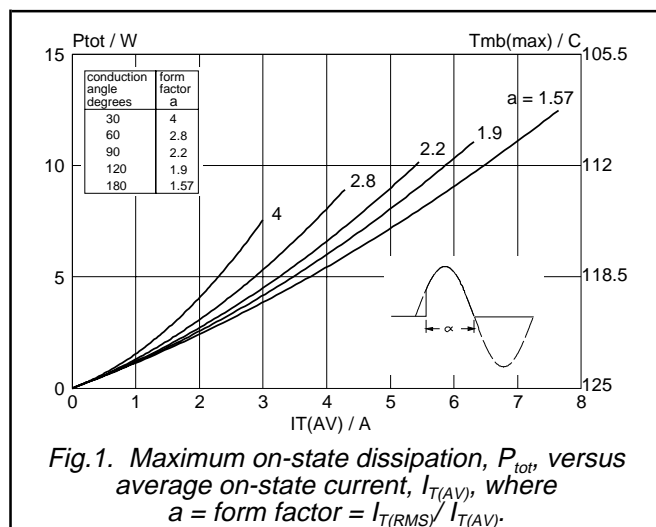
### DYNAMIC CHARACTERISTICS

$T_j = 25\text{ °C}$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$dV_D/dt$	Critical rate of rise of off-state voltage	$V_D = 67\% V_{DRM(max)}$ ; $T_j = 125\text{ °C}$ ; exponential waveform				
$t_{gt}$	Gate controlled turn-on time	Gate open circuit $R_{GK} = 100\ \Omega$	50	130	-	V/ $\mu$ s
		$I_{TM} = 40\text{ A}$ ; $V_D = V_{DRM}$ ; $I_G = 0.1\text{ A}$ ; $di_G/dt = 5\text{ A}/\mu$ s	200	1000	-	V/ $\mu$ s
$t_q$	Circuit commutated turn-off time	$V_D = 67\% V_{DRM(max)}$ ; $I_{TM} = 20\text{ A}$ ; $V_R = 25\text{ V}$ ; $di_{TM}/dt = 30\text{ A}/\mu$ s; $dV_D/dt = 50\text{ V}/\mu$ s; $R_{GK} = 100\ \Omega$	-	70	-	$\mu$ s

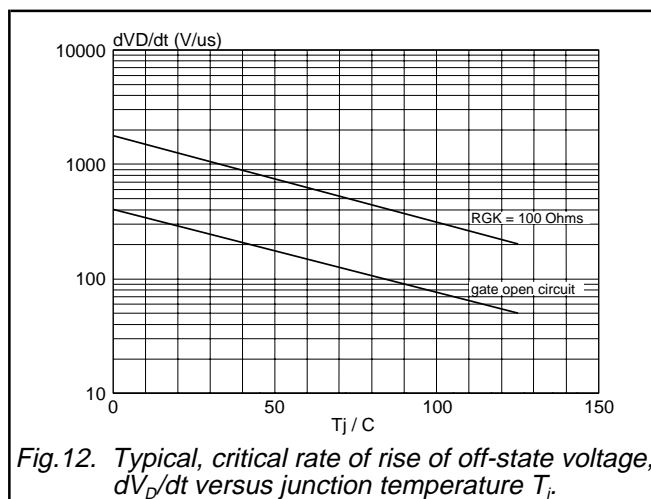
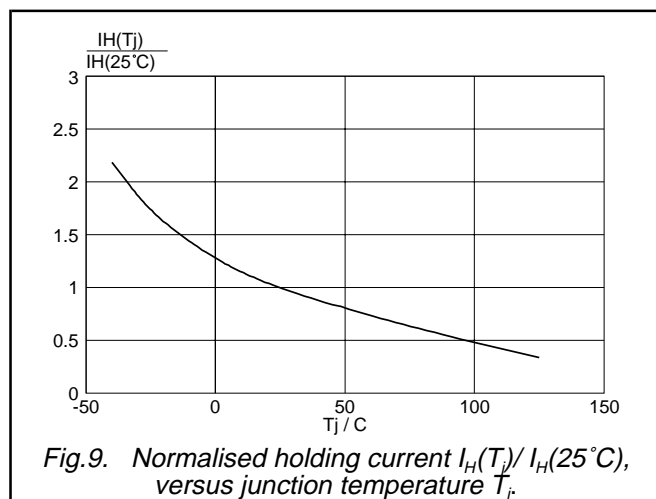
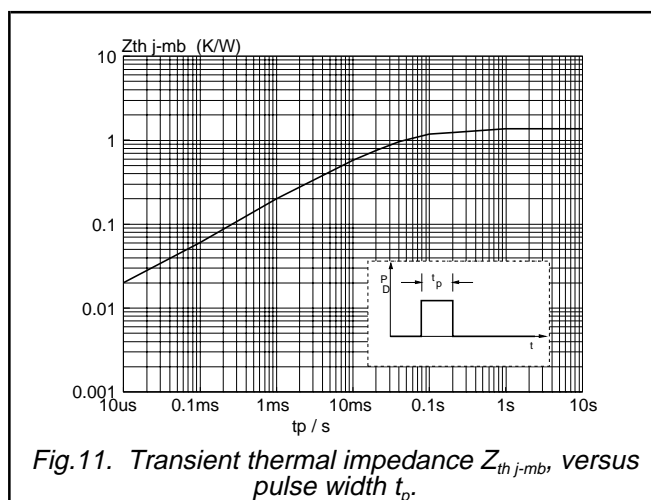
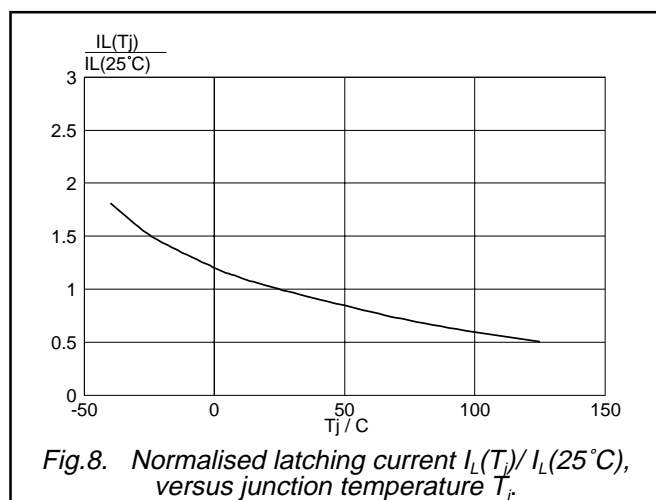
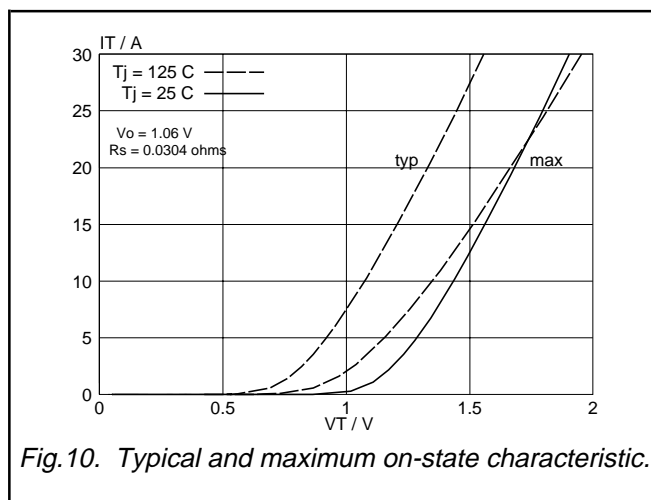
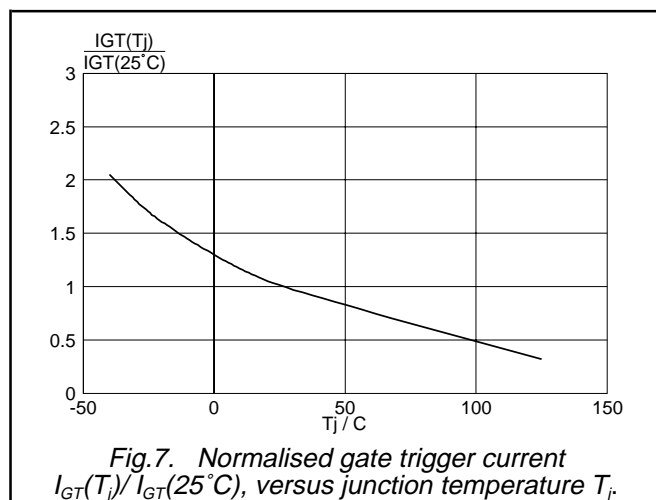
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## MECHANICAL DATA

Dimensions in mm

Net Mass: 0.8 g

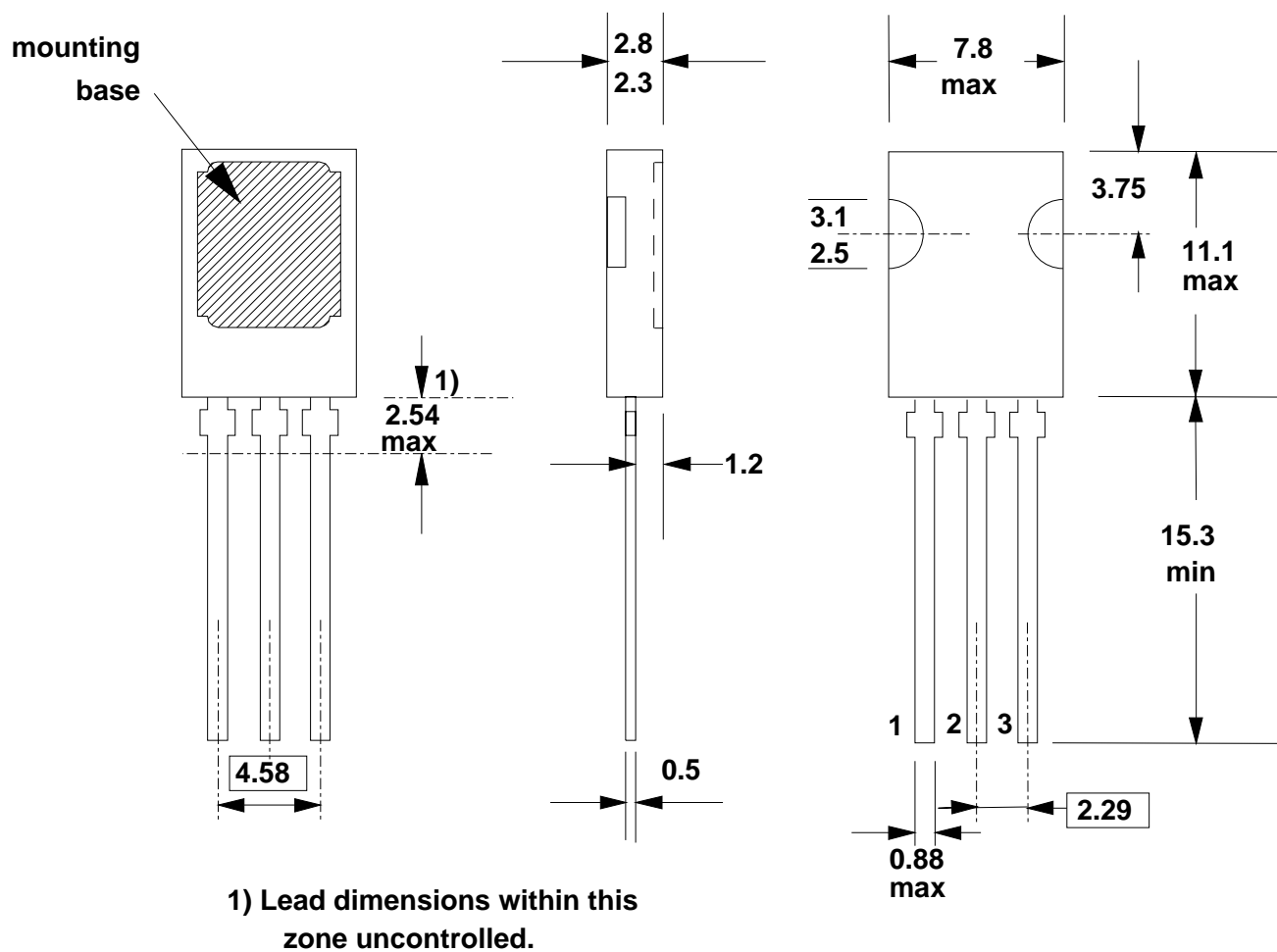


Fig.13. SOT82; pin 2 connected to mounting base.

### Notes

1. Refer to mounting instructions for SOT82 envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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### DEFINITIONS

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	
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